

VS-10ETF10FP-M3, VS-10ETF12FP-M3

Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 10 A



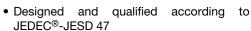


2L TO-220 FullPAK

PRIMARY CHARACTERISTICS					
I _{F(AV)}	10 A				
V_{R}	1000 V, 1200 V				
V _F at I _F	1.33 V				
I _{FSM}	140 A				
t _{rr}	80 ns				
T _J max.	150 °C				
Snap factor	0.6				
Package	2L TO-220 FullPAK				
Circuit configuration	Single				

FEATURES

- · Glass passivated pellet chip junction
- 150 °C max. operation junction temperature





- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL pending
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-10ETF1..FP... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
V _{RRM}		1000, 1200	V			
I _{F(AV)}	Sinusoidal waveform	10	A			
I _{FSM}		140	A			
t _{rr}	1 A, 100 A/μs	80	ns			
V _F	10 A, T _J = 25 °C	1.33	V			
TJ		-40 to +150	°C			

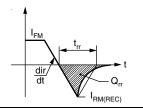
VOLTAGE RATINGS						
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA			
VS-10ETF10FP-M3	1000	1100	4			
VS-10ETF12FP-M3	1200	1300	4			

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ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I _{F(AV)}	T _C = 95 °C, 180° conduction half sine wave	10	
Maximum peak one cycle		10 ms sine pulse, rated $V_{\mbox{\scriptsize RRM}}$ applied	115	Α
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	140	
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	66	A ² s
	1-1	10 ms sine pulse, no voltage reapplied	94	A-S
Maximum I ² √t for fusing	I²√t	t = 0.1 to 10 ms, no voltage reapplied	940	A²√s

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V_{FM}	10 A, T _J = 25 °C		1.33	V
Forward slope resistance	rt	- T _J = 150 °C		22.9	mΩ
Threshold voltage	V _{F(TO)}			0.96	V
Maximum rayaraa laakaga aurrant		T _J = 25 °C	V _B = Rated V _{BBM}	0.1	mA
Maximum reverse leakage current	I _{RM}	T _J = 150 °C	4	11/4	

RECOVERY CHARACTERISTICS					
PARAMETER SYMBOL TEST CONDITIONS VALUES UNITS					
Reverse recovery time	t _{rr}	L at 10 A	310	ns	
Reverse recovery current	I _{rr}	I _F at 10 A _{pk} 25 A∕µs 25 °C	4.7	Α	
Reverse recovery charge	Q _{rr}	25 0	1.05	μC	
Snap factor	S		0.6		



THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and sto temperature range	orage	T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resistar junction to case	nce	R _{thJC}	DC operation	2.5	
Maximum thermal resistar junction to ambient	nce	R _{thJA}		62	°C/W
Typical thermal resistance case to heatsink	Э,	R _{thCS}	Mounting surface, smooth, and greased	0.5	
Approximate weight				2	g
Approximate weight				0.07	OZ.
Manuation toward	minimum			6 (5)	kgf · cm
Mounting torque m	maximum			12 (10)	(lbf ⋅ in)
Marking device			Case style 2L TO-220 FullPAK	10ETF10FP 10ETF12FP	

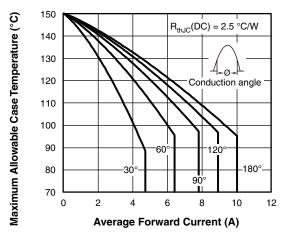


Fig. 1 - Current Rating Characteristics

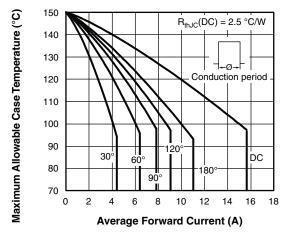


Fig. 2 - Current Rating Characteristics

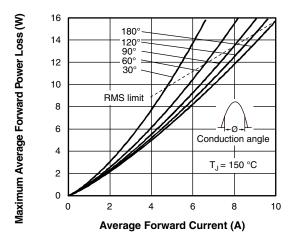


Fig. 3 - Forward Power Loss Characteristics

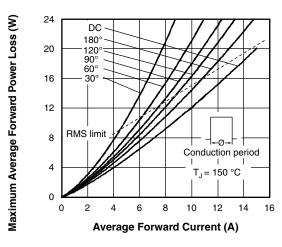


Fig. 4 - Forward Power Loss Characteristics

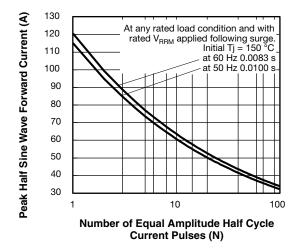


Fig. 5 - Maximum Non-Repetitive Surge Current

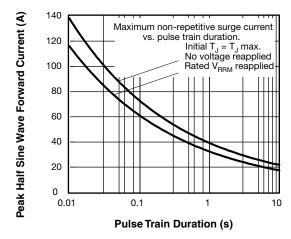


Fig. 6 - Maximum Non-Repetitive Surge Current

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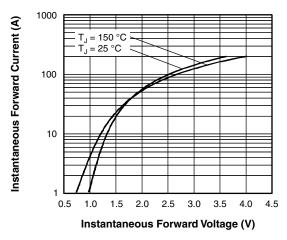


Fig. 7 - Forward Voltage Drop Characteristics

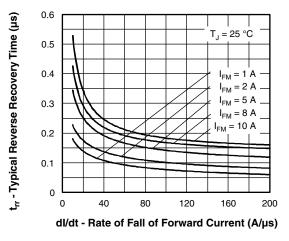


Fig. 8 - Recovery Time Characteristics, $T_J = 25$ °C

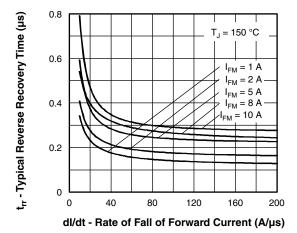


Fig. 9 - Recovery Time Characteristics, $T_J = 150 \, ^{\circ}\text{C}$

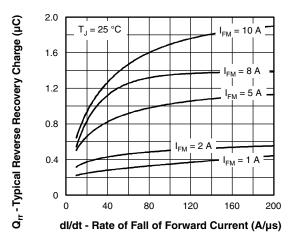


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

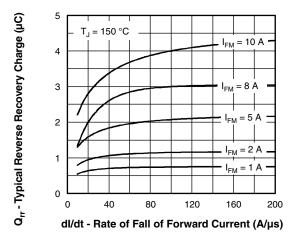


Fig. 11 - Recovery Charge Characteristics, $T_J = 150 \, ^{\circ}\text{C}$

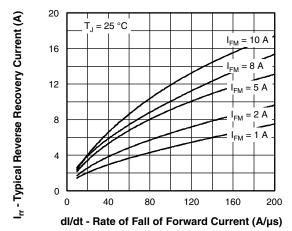


Fig. 12 - Recovery Current Characteristics, $T_J = 25\ ^{\circ}\text{C}$

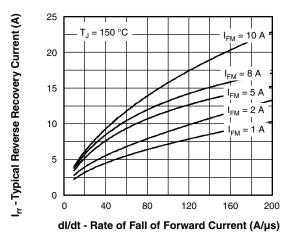


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

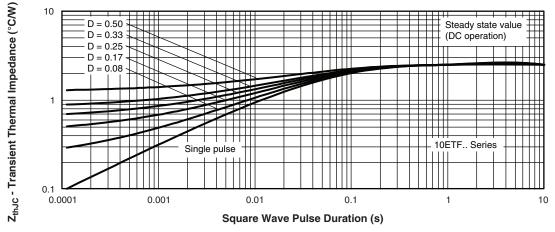


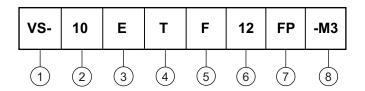
Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

VS-10ETF10FP-M3, VS-10ETF12FP-M3

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (10 = 10 A)

- Circuit configuration:

E = single diode

4 - Package:

T = TO-220

5 - Type of silicon:

F = fast soft recovery rectifier

02 = 200 V 04 = 400 V

Voltage code x 100 = V_{RRM}

06 = 600 V

7 - FullPAK

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-10ETF10FP-M3	50	1000	Antistatic plastic tubes		
VS-10ETF12FP-M3	50	1000	Antistatic plastic tubes		

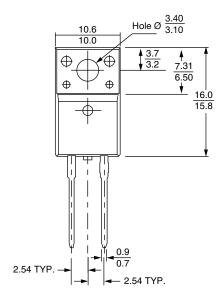
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?96157</u>				
Part marking information	www.vishay.com/doc?95392			

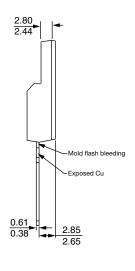


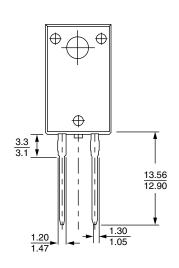
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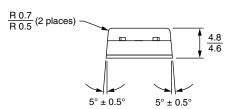
2L TO-220 FullPAK

DIMENSIONS in millimeters









Bottom view

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Vishay

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